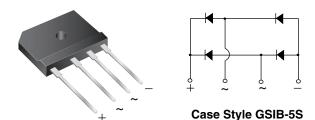


GSIB620N, GSIB640N, GSIB660N, GSIB680N

Vishay General Semiconductor

Single-Phase Single In-Line Bridge Rectifiers



PRIMARY CHARACTERISTICS					
Package	GSIB-5S				
I _{F(AV)}	6.0 A				
V _{RRM}	200 V, 400 V, 600 V, 800 V				
I _{FSM}	180 A				
I _R	10 µA				
V _F	0.95 V				
T _J max.	150 °C				
Diode variations	In-Line				

FEATURES

- UL recognition file number E54214
- Thin single in-line package
- Glass passivated chip junction
- High surge current capability
- High case dielectric strength of 1500 V_{RMS}
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home appliances, office equipment, industrial automation applications.

MECHANICAL DATA

Case: GSIB-5S

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked on body

Mounting Torque: 10 cm-kg (8.8 in-lbs) maximum

Recommended Torque: 5.7 cm-kg (5 in-lbs)

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER		SYMBOL	GSIB620N	GSIB640N	GSIB660N	GSIB680N	UNIT
Maximum repetitive peak reverse voltage		V _{RRM}	200	400	600	800	V
Maximum RMS voltage		V _{RMS}	140	280	420	560	V
Maximum DC blocking voltage		V _{DC}	200	400	600	800	V
Maximum average forward rectified	T _C = 100 °C	I _{F(AV)} ⁽¹⁾		A			
output current at	T _A = 25 °C	I _{F(AV)} ⁽²⁾	2.8				
Peak forward surge current single sine-wave superimposed on rated load (JEDEC method)		I _{FSM}	180			А	
Rating for fusing (t < 8.3 ms)		l ² t	120			A ² s	
Operating junction and storage temperature range		T _J , T _{STG}		- 55 to) + 150		°C

Notes

⁽¹⁾ Unit case mounted on aluminum plate heatsink

⁽²⁾ Units mounted on PCB with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length

1





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	GSIB620N	GSIB640N	GSIB660N	GSIB680N	UNIT
Maximum instantaneous forward voltage drop per diode	I _F = 3.0 A	V _F	0.95			V	
Maximum DC reverse current at	T _A = 25 °C	I_	10				μA
rated DC blocking voltage per diode	T _A = 125 °C	IR	250			μΑ	

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL GSIB620N GSIB640N GSIB660N GSIB680N UN				UNIT	
Maximum thermal resistance	R _{0JA} ⁽²⁾	22				°C/W
	R _{0JC} ⁽¹⁾		3	.4		0/10

Notes

⁽¹⁾ Unit case mounted on aluminum plate heatsink

⁽²⁾ Units mounted on PCB with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length

⁽³⁾ Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE BASE QUANTITY DELIVERY					
GSIB660N-M3/45	7.0	45	20	Tube			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

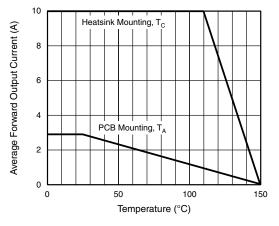


Fig. 1 - Derating Curve Output Rectified Current

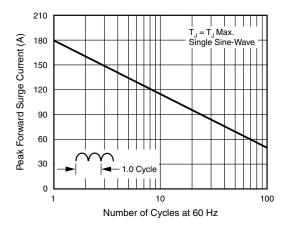


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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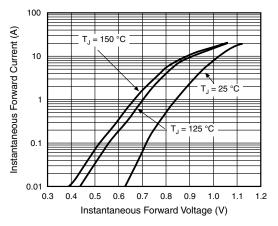


Fig. 3 - Typical Forward Characteristics Per Diode

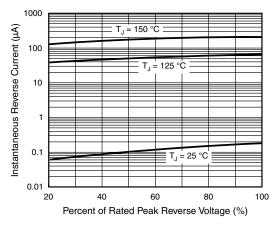


Fig. 4 - Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

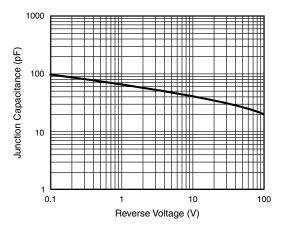


Fig. 5 - Typical Junction Capacitance Per Diode

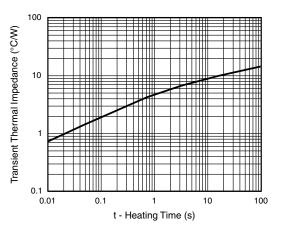
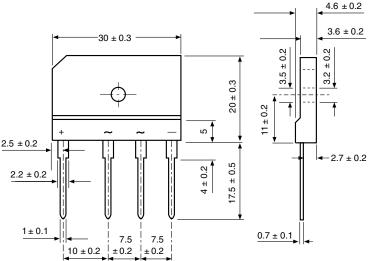


Fig. 6 - Typical Transient Thermal Impedance Per Diode





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